N-Channel 200-V (D-S) MOSFET

PRODUCT SUMMARY		
$V_{(BR)DSS}$ (V)	$r_{DS(on)}$ (Ω)	I_D (A)
200	0.122 at V_{GS} = 10 V	25

RoHS* COMPLIANT

FEATURES

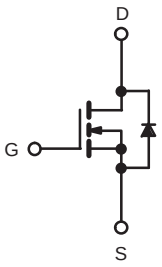
- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 % R_g and UIS tested

APPLICATIONS

- LCD/LED TV
- Consumer Appliances
- Lighting
- AC-DC Power Supply

D²PAK
(TO-263)

Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-Source Voltage			V_{DS}	200	V
Gate-Source Voltage			V_{GS}	± 20	
Continuous Drain Current	V_{GS} at 10 V	T_C = 25 °C	I_D	25[a]	A
		T_C = 100 °C		18[a]	
Pulsed Drain Current			I_{DM}	100	
Single Pulse Avalanche Energy			E_{AS}	365	mJ
Avalanche Current			I_{AR}	25	A
Repetiitive Avalanche Energy			E_{AR}	14	mJ
Maximum Power Dissipation	T_C = 25 °C		P_D	3.1[c]	W
	T_A = 25 °C[b]			130	
Peak Diode Recovery dV/dt			dV/dt	5.0	V/ns
Operating Junction and Storage Temperature Range			T_J, T_{stg}	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature)	for 10 s			300	

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Maximum Junction-to-Ambient (PCB Mounted, Steady-State)	R_{thJA}	-	65	°C/W
Maximum Junction-to-Case (Drain)	R_{thJC}	-	4.98	

a. Package limited.
b. When Mounted on 1" square PCB (FR-4 material).
c. See SOA curve for voltage derating.

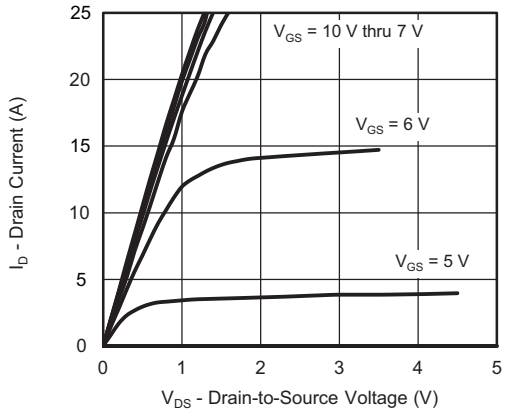
SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	200	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	2	-	4	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 160 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 160 V, V_{GS} = 0 V, T_J = 125 °C	-	-	100	
		V_{DS} = 160 V, V_{GS} = 0 V, T_J = 175 °C	-	-	2	mA
On-State Drain Current [a]	$I_{D(on)}$	V_{DS} ≥ 10 V, V_{GS} = 10 V	25	-	-	A
Drain-Source On-State Resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 10 A	-	0.122	0.145	Ω
		V_{GS} = 7.5 V, I_D = 8 A	-	0.135	0.158	
Forward Transconductance [a]	g_{fs}	V_{DS} = 20 V, I_D = 10 A	-	15	-	S
Dynamic [b]						
Input Capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 160 V, f = 1 MHz	-	2450	-	pF
Output Capacitance	C_{oss}			350		
Reverse Transfer Capacitance	C_{rss}		-	90	-	
Total Gate Charge [c]	Q_g	V_{DS} = 160 V, V_{GS} = 10 V, I_D = 10 A	-	25	41	nC
Gate-Source Charge [c]	Q_{gs}			4.5		
Gate-Drain Charge [c]	Q_{gd}			13		
Gate Resistance	R_g	f = 1 MHz		3.9		Ω
Turn-On Delay Time [c]	$t_{d(on)}$	V_{DD} = 160 V, R_L = 1.67 Ω I_D ≅ 10 A, V_{GEN} = 10 V, R_g = 1 Ω		15	26	ns
Rise Time [c]	t_r			25	44	
Turn-Off Delay Time [c]	$t_{d(off)}$		-	27	54	
Fall Time [c]	t_f		-	9	20	
Drain-Source Body Diode Ratings and Characteristics [b] (T_C = 25 °C)						
Pulsed Current (t = 100 µs)	I_{SM}		-	-	100	A
Forward Voltage [a]	V_{SD}	I_F = 20 A, V_{GS} = 0 V		0.75	1.5	V
Reverse Recovery Time	t_{rr}	I_F = 20 A, d /dt = 100 A/µs	-	88	176	ns
Peak Reverse Recovery Charge	$I_{RM(REC)}$		-	5	10	A
Reverse Recovery Charge	Q_{rr}			0.22	0.44	µC

Notes

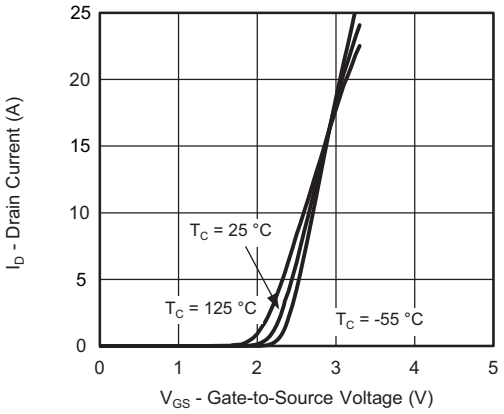
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

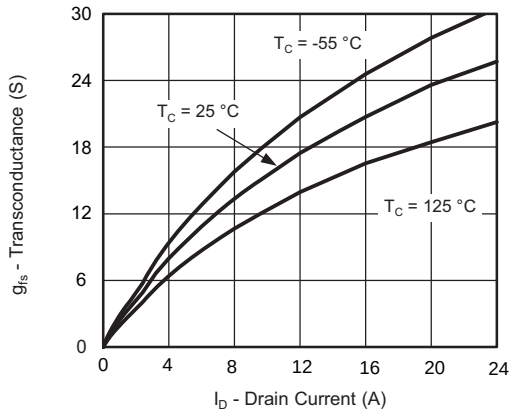
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



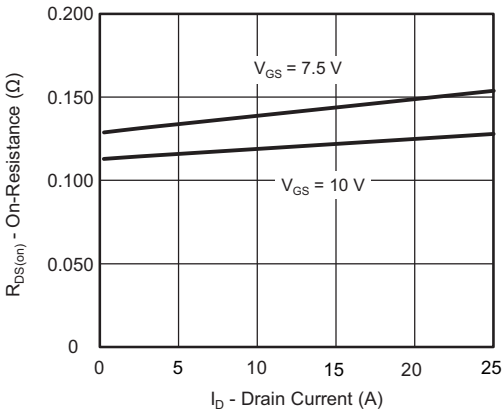
Output Characteristics



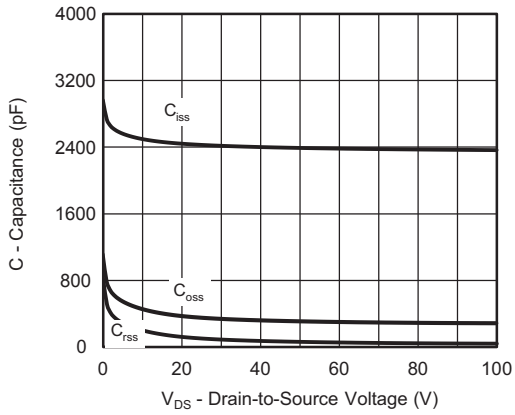
Transfer Characteristics



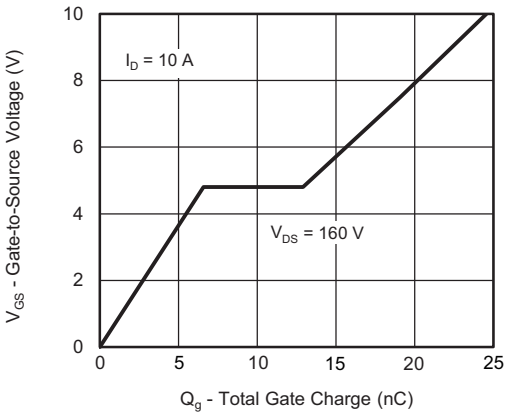
Transconductance



On-Resistance vs. Drain Current

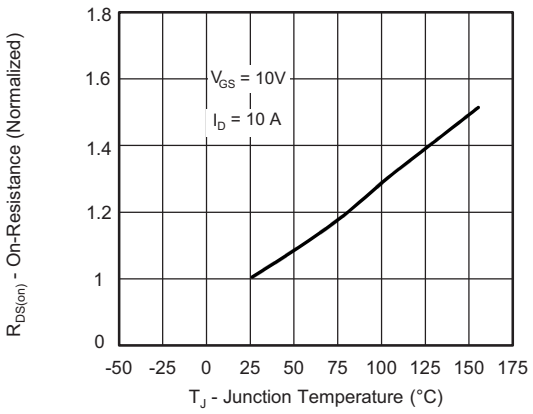


Capacitance

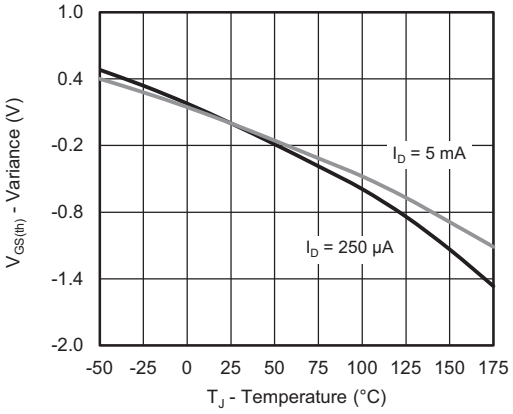


Gate Charge

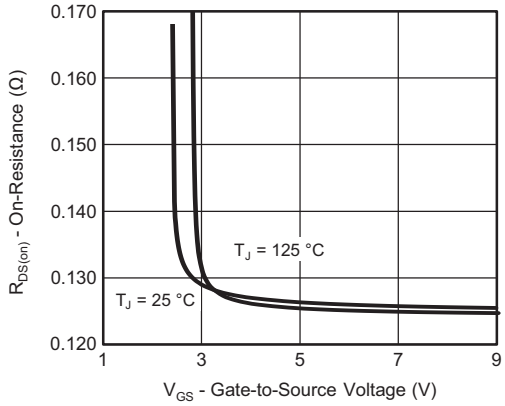
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



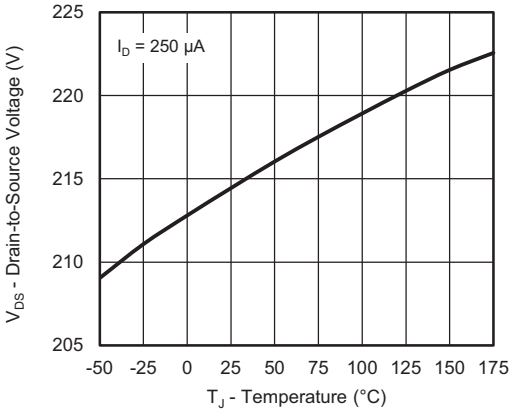
On-Resistance vs. Junction Temperature



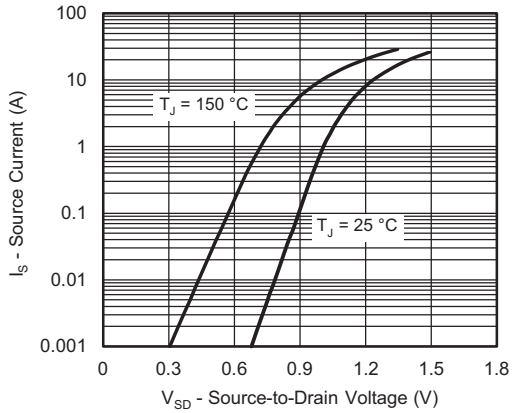
Threshold Voltage



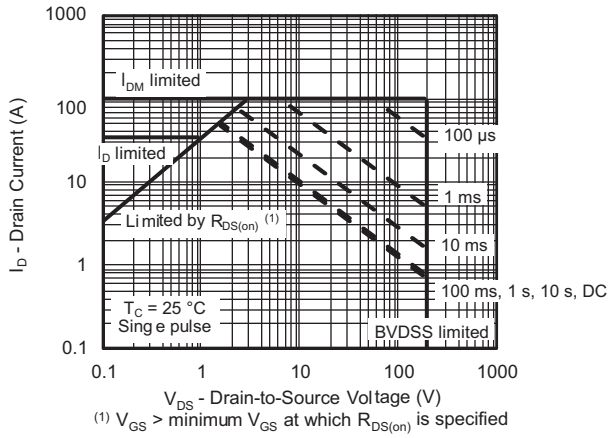
On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature



Source Drain Diode Forward Voltage



Safe Operating Area

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

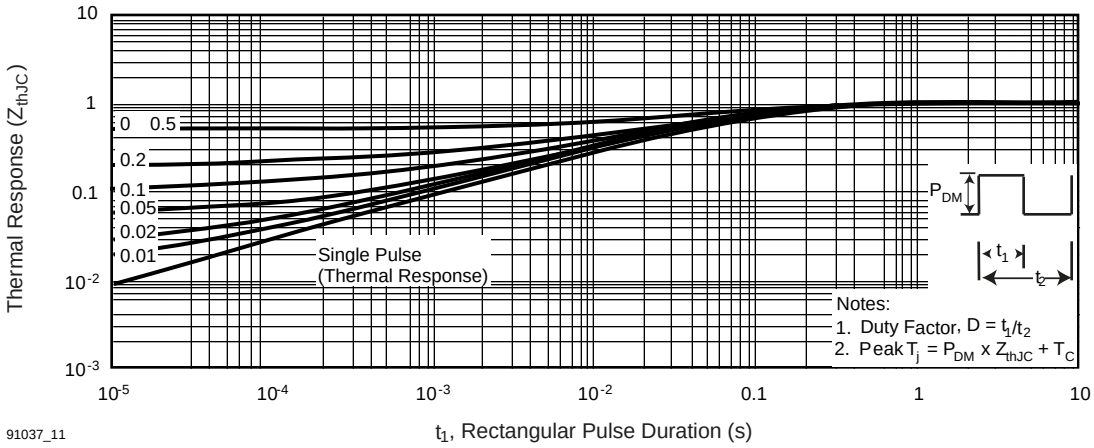
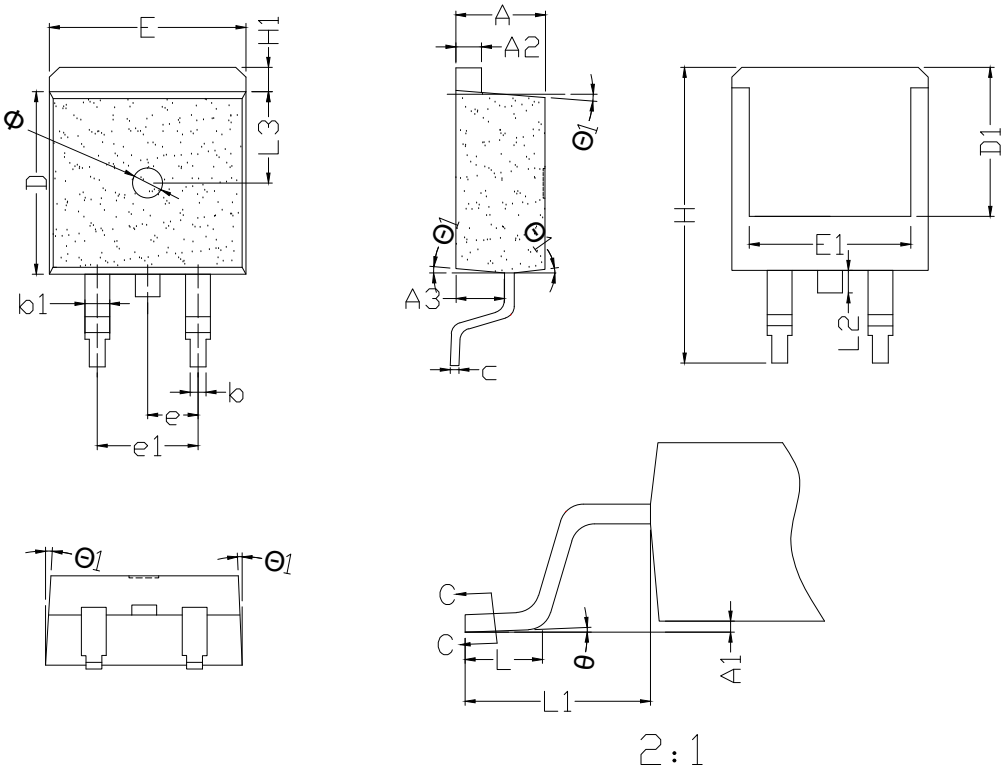


Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

TO-263 PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	4.10	4.50	4.80	e	2.35	2.54	2.75
A1	0.00	0.10	0.30	e1		5.08REF	
A2	1.10	1.30	1.50	H	14.50	15.15	16.00
A3	2.15	2.50	3.10	H1	1.00	1.28	1.75
b	0.60	0.80	1.05	L	1.80	2.23	2.90
b1	1.05	1.33	1.50	L1	4.30	4.75	5.50
c	0.33	0.50	0.66	L2	1.00	1.30	1.85
D	8.40	9.20	9.60	L3	0.90	4.65	9.00
D1		7.50REF		ϕ	0°	2°	5°
E	9.60	10.02	10.80	ϕ1	2°	-	7°
E1	7.60	9.88	10.30	Φ		1.5BSC	

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